Application No.: 10/665,253

## **CLAIM AMENDMENTS**

1. (Currently amended) A spin driven resistor comprising:

a magnetic body having a resistance and a resonance frequency, said resistance capable of changing in response to an applied magnetic field while in the presence of an electromagnetic field;

two wires, each said wire in electrical communication with said magnetic body; and

a voltage source in electrical communication with [[each]] said [[wire]] magnetic body so as to place a potential across said magnetic body, wherein said magnetic body reaches a maximum value of change in resistance when said magnetic body is subjected to an externally applied magnetic field while in the presence of an externally applied electromagnetic field.

- 2. (Original) The spin driven resistor according to claim 1 wherein said magnetic body comprises a material selected from the group consisting of metallic and semiconducting magnets.
- 3. (Original) The spin driven resistor according to claim 1 wherein said magnetic body comprises vanadium di-tetracyanoethanide.
- 4. (Original) The spin driven resistor according to claim 1 wherein said spin driven resistor is subjected to said externally applied electromagnetic field while at a constant temperature.

- 5. (Original) The spin driven resistor according to claim 1 wherein said spin driven resistor is subjected to said externally applied magnetic field while at a constant temperature.
- 6. (Original) The spin driven resistor according to claim 1 wherein said externally applied magnetic field is an externally applied direct-current magnetic field.
- 7. (Original) The spin driven resistor according to claim 1 wherein said externally applied electromagnetic field comprises microwave radiation.
- 8. (Original) The spin driven resistor according to claim 7 wherein said microwave radiation has a power in the range of about 1 mW to about 25 mW.
- 9. (Original) The spin driven resistance according to claim 1 wherein said maximum value of change in resistance increases as said electromagnetic field increases in power.
- 10. (Original) The spin driven resistance according to claim 1 wherein said maximum value of change in resistance decreases as temperature increases.